

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: CHENG et al.

Examiner: Everhart, Caridad

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Title: METHODS AND APPARATUS FOR THE OPTIMIZATION OF PHOTO RESIST ETCHING IN A PLASMA PROCESSING

SYSTEM

INFORMATION DISCLOSURE STATEMENT

US PATENT DOCUMENTS

Examiner	Cite	Document Number	Publication Date	Name of Patentee or	Reference to Related Case
Initials	No.			Applicant	
CME	1	6,083,844	2000-07-04	Bui-Le et al.	
Come	2	6,297163	2001-10-02	Zhu et al.	
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CME.	No. 4	Ellingboe, Bert, "Plasma Processing In The Microelectronics Industry", Plasma Research Laboratory, paper.			
ame	5	"Research", http://graves-lab.cchem.berkeley.edu/~humbird/research/			
eme	6	Lassig et al., "Selective Removal Strategies for Low k Dual Damascene", Semiconductor Fabtech, pp 185-190			
cone come	7	EEE435/591 Microelectronics: Lecture 16: Back-end Processes			
come	8	EE 539TM/M(S)E 599TM – Lecture C2: Lithography-based Systems			
OGNE	9	Hanawa, Tesuro (Group 1), "Current Status of Photolithography/Etching", Semiconductor Leading Edge Technologies, Inc. May 31, 2000 Selete Program Update			
Come	10	Jones et al., "Micro Photocell Monitoring Finds the Killers", Summer 2003, Yield Management Solutions, pp. 38-45			
ame	11	Woods, Eric, "Plasma Etching", CMOS Group, Microelectronics Research Center, Georgia Institute of Technology			
COME	12	Muscat, Anthony, "Gas Phase Cleaning of Silicon Wafer Surfaces", http://www.che.arizona.edu/directory/faculty/muscat/research/Tutorials/Gas_Phase_Wafer_Clean.html			
<u>CME</u>	13	Spitzlsperger, Gerhard, "Introduction to Low Pressure Glow Discharges for Semiconductor Manufacturing with Special Emphasis on Plasma Etching", http://www.gs68.de/tutorials/plasma/node26.html			

Examiner C. Ruckas	Date Considered -4-15-05-
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